

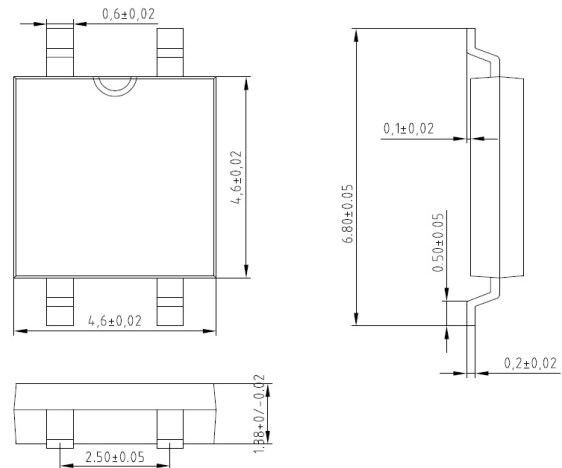


FEATURES

- Glass passivated chip junction
- Ideal for surface mounted applications
- Low leakage
- High forward surge current capability
- High temperature soldering guaranteed:
260°C/10 seconds at terminals

MECHANICAL DATA

- Case: Molded plastic body
- Epoxy: UL94V-0 rate flame retardant
- Polarity: Molded on body
- LeadP: Plated terminals solderable per MIL-STD-202E method 208C
- Weight: 0.04 ounce, 1.0 gram



MAXIMUM RATINGS AND ELECTRICAL CHARACTERISTICS

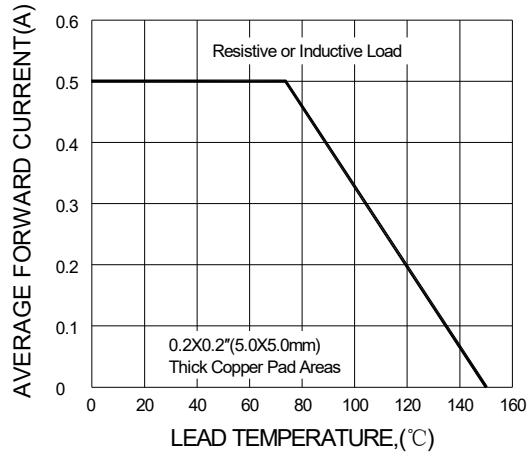
- Ratings at 25°C ambient temperature unless otherwise specified
- Single Phase, half wave, 60Hz, resistive or inductive load
- For capacitive load derate current by 20%

	SYMBOLS	MB1F	MB2F	MB3F	MB4F	MB6F	MB8F	MB10F	UNIT
Maximum Reverse Peak Repetitive Voltage	V_{RRM}	50	100	200	400	600	800	1000	Volts
Maximum RMS Voltage	V_{RMS}	35	70	140	280	420	560	700	Volts
Maximum DC Blocking Voltage	V_{DC}	50	100	200	400	600	800	1000	Volts
Maximum Average Forward Rectified Output Current, 0.06"(1.5mm) lead length at $T_A=40^\circ\text{C}$ (Note 2)	$I_{(AV)}$	0.5							Amps
Peak Forward Surge Current 8.3ms single half sine wave superimposed on rated load (JEDEC Method)	I_{FSM}	20							Amps
Rating for Fusing ($t < 8.3\text{ms}$)	I^2t	10							A^2s
Maximum Instantaneous Forward Voltage drop Per Bridge element 1.0A	V_F	1.1							Volts
Maximum Reverse Current at rated DC blocking voltage per element	$T_A=25^\circ\text{C}$	I_R							μAmps
	$T_A=125^\circ\text{C}$	0.5							mAmps
Typical Junction Capacitance (NOTE 1)	C_J	13							$^\circ\text{C/W}$
Typical Thermal Resistance (NOTE 2)	$R_{\theta JA}$	40							V_{AC}
Operating and Storage Temperature Range	T_J, T_{STG}	(-55 to +150)							$^\circ\text{C}$

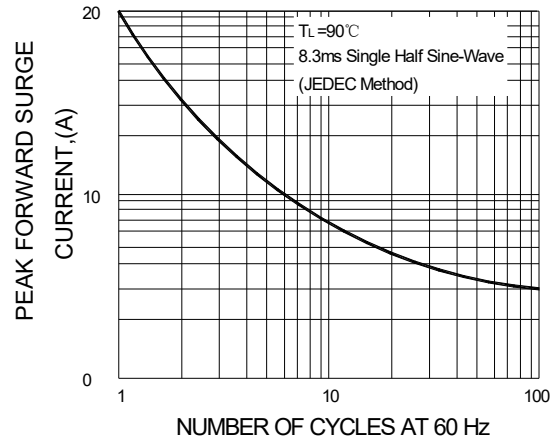
- Notes:**
1. Measured at 1.0MHz and applied reverse voltage of 4.0 Volts.
 2. Unit mounted on P.C.B. with 0.95"×1.15" copper pads.



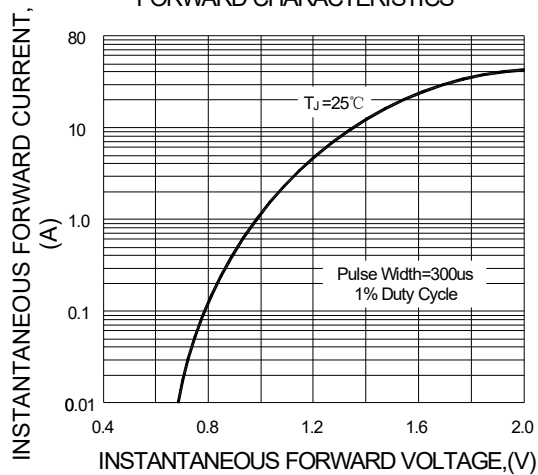
F1G.1-FORWARD CURRENT
DERATING CURVE



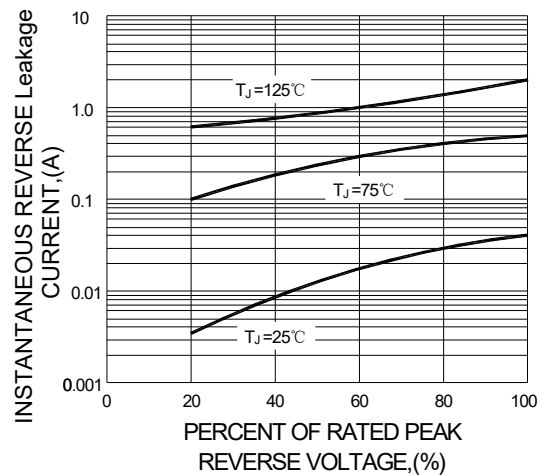
F1G.2-MAXIMUM NON-REPETITIVE PEAK
FORWARD SURGE CURRENT



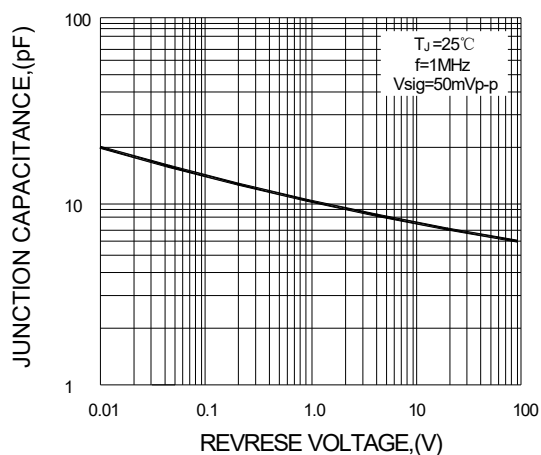
F1G.3-TYPICAL INSTANTANEOUS
FORWARD CHARACTERISTICS



F1G.4-TYPICAL REVERSE
CHARACTERISTICS



F1G.5-TYPICAL JUNCTION CAPACITANCE



F1G.6-TRANSIENT THERMAL IMPEDANCE

